NSN 5961-01-209-2291

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-209-2291 **Inclosure Material:** Metal **Overall Length:** 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.335 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 475.0 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 milliamperes forward current, average absolute **Power Rating Per Characteristic:** 0.1 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 70.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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